Infineon Technologies - XMC4700F144F2048AAXQMA1 Datasheet

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Applications of "Embedded - Microcontrollers"

Details	
Product Status	Active
Core Processor	ARM® Cortex®-M4
Core Size	32-Bit Single-Core
Speed	144MHz
Connectivity	CANbus, EBI/EMI, Ethernet, I²C, LINbus, MMC/SD, SPI, UART/USART, USB OTG, USIC
Peripherals	DMA, I²S, LED, POR, Touch-Sense, WDT
Number of I/O	119
Program Memory Size	2MB (2M x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	352K x 8
Voltage - Supply (Vcc/Vdd)	3.13V ~ 3.63V
Data Converters	A/D 32x12b; D/A 2x12b
Oscillator Type	External
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	144-LQFP Exposed Pad
Supplier Device Package	PG-LQFP-144-24
Purchase URL	https://www.e-xfl.com/product-detail/infineon-technologies/xmc4700f144f2048aaxqma1

XMC4[78]00 Data Sheet

Revision History: V1.0 2016-01

Previous Versions:
V0.7 2015-10 (preliminary)

Page	Subjects
8	Corrected EtherCAT features to 8 Fieldbus Memory Management Units (FMMU) and 8 Sync Manager.
46	Added footnote explaining minimum V_{BAT} requirements to start the hibernate domain and/or oscillation of a crystal on RTC_XTAL.
53	Added HIBIO characteristics.
58	Corrected DAC INL and gain error.
70	Changed frequency dependency of the current consumption.
73	Added peripheral idle current overview.
127ff	Updated package parameters and drawings.
132	Higher HBM and CDM ESD limits.

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Table 5 SRAM Memory Ranges

Total SRAM Size	Program SRAM	System Data SRAM	Communication Data SRAM
200 Kbytes	1FFE E000$_H$ – 1FFF FFFF$_H$	2000 0000$_H$ – 2001 FFFF$_H$	–
276 Kbytes	1FFE 8000$_H$ – 1FFF FFFF$_H$	2000 0000$_H$ – 2001 FFFF$_H$	2002 0000$_H$ – 2002 CFFF$_H$
352 Kbytes	1FFE 8000$_H$ – 1FFF FFFF$_H$	2000 0000$_H$ – 2001 FFFF$_H$	2002 0000$_H$ – 2003 FFFF$_H$

Table 6 ADC Channels[1)]

Package	VADC G0	VADC G1	VADC G2	VADC G3
PG-LQFP-144 PG-LFBGA-196	CH0..CH7	CH0..CH7	CH0..CH7	CH0..CH7
PG-LQFP-100	CH0..CH7	CH0..CH7	CH0..CH3	CH0..CH3

1) Some pins in a package may be connected to more than one channel. For the detailed mapping see the Port I/O Function table.

1.5 Identification Registers

The identification registers allow software to identify the marking.

Table 7 XMC4700 Identification Registers

Register Name	Value	Marking
SCU_IDCHIP	0004 7001$_H$	EES-AA, ES-AA, AA
JTAG IDCODE	101D F083$_H$	EES-AA, ES-AA, AA

Table 8 XMC4800 Identification Registers

Register Name	Value	Marking
SCU_IDCHIP	0004 8001$_H$	EES-AA, ES-AA, AA
JTAG IDCODE	101D F083$_H$	EES-AA, ES-AA, AA

2 General Device Information

This section summarizes the logic symbols and package pin configurations with a detailed list of the functional I/O mapping.

2.1 Logic Symbols

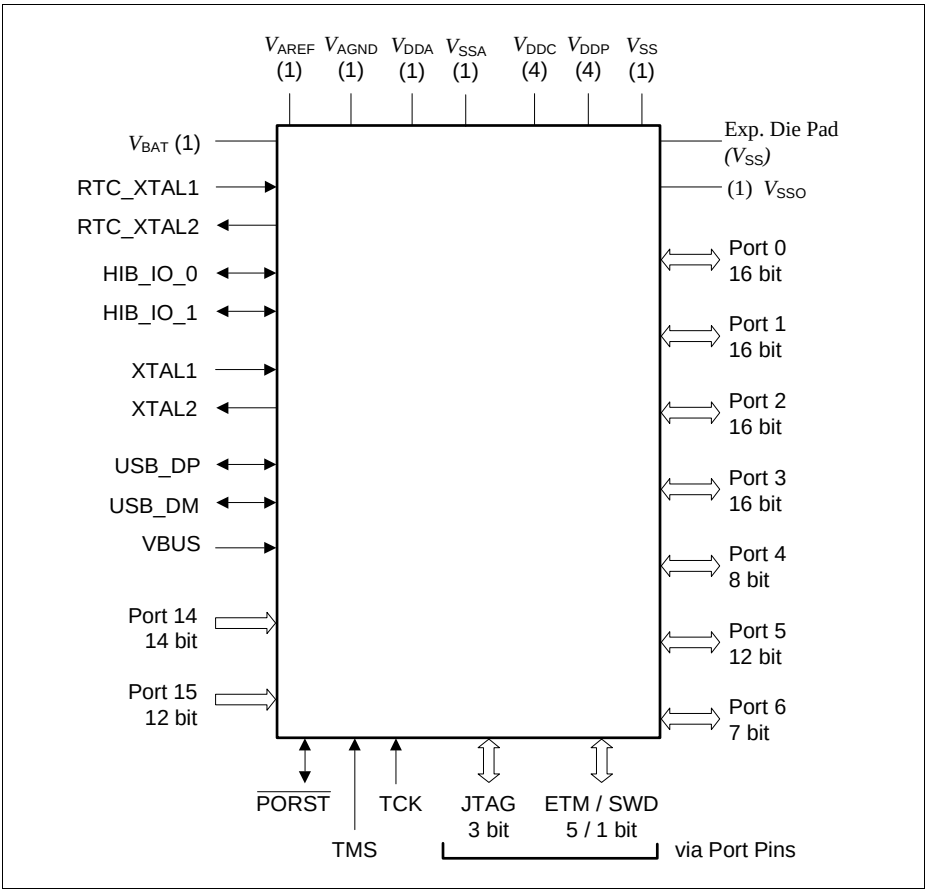
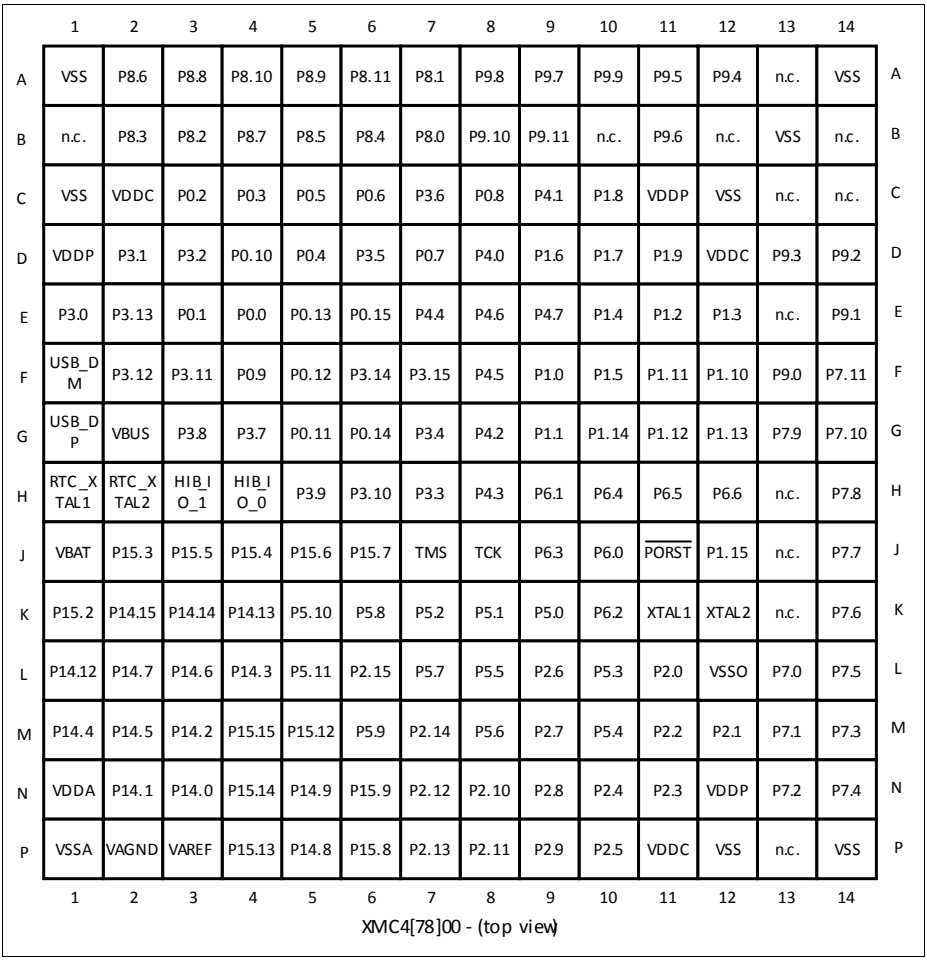


Figure 2 XMC4[78]00 Logic Symbol PG-LQFP-144



	1	2	3	4	5	6	7	8	9	10	11	12	13	14	
A	VSS	P8.6	P8.8	P8.10	P8.9	P8.11	P8.1	P9.8	P9.7	P9.9	P9.5	P9.4	n.c.	VSS	A
B	n.c.	P8.3	P8.2	P8.7	P8.5	P8.4	P8.0	P9.10	P9.11	n.c.	P9.6	n.c.	VSS	n.c.	B
C	VSS	VDDC	P0.2	P0.3	P0.5	P0.6	P3.6	P0.8	P4.1	P1.8	VDDP	VSS	n.c.	n.c.	C
D	VDDP	P3.1	P3.2	P0.10	P0.4	P3.5	P0.7	P4.0	P1.6	P1.7	P1.9	VDDC	P9.3	P9.2	D
E	P3.0	P3.13	P0.1	P0.0	P0.13	P0.15	P4.4	P4.6	P4.7	P1.4	P1.2	P1.3	n.c.	P9.1	E
F	USB_DM	P3.12	P3.11	P0.9	P0.12	P3.14	P3.15	P4.5	P1.0	P1.5	P1.11	P1.10	P9.0	P7.11	F
G	USB_DP	VBUS	P3.8	P3.7	P0.11	P0.14	P3.4	P4.2	P1.1	P1.14	P1.12	P1.13	P7.9	P7.10	G
H	RTC_XTAL1	RTC_XTAL2	HIB_IO_1	HIB_IO_0	P3.9	P3.10	P3.3	P4.3	P6.1	P6.4	P6.5	P6.6	n.c.	P7.8	H
J	VBAT	P15.3	P15.5	P15.4	P15.6	P15.7	TMS	TCK	P6.3	P6.0	$\overline{\text{PORST}}$	P1.15	n.c.	P7.7	J
K	P15.2	P14.15	P14.14	P14.13	P5.10	P5.8	P5.2	P5.1	P5.0	P6.2	XTAL1	XTAL2	n.c.	P7.6	K
L	P14.12	P14.7	P14.6	P14.3	P5.11	P2.15	P5.7	P5.5	P2.6	P5.3	P2.0	VSSO	P7.0	P7.5	L
M	P14.4	P14.5	P14.2	P15.15	P15.12	P5.9	P2.14	P5.6	P2.7	P5.4	P2.2	P2.1	P7.1	P7.3	M
N	VDDA	P14.1	P14.0	P15.14	P14.9	P15.9	P2.12	P2.10	P2.8	P2.4	P2.3	VDDP	P7.2	P7.4	N
P	VSSA	VAGND	VAREF	P15.13	P14.8	P15.8	P2.13	P2.11	P2.9	P2.5	VDDC	VSS	n.c.	VSS	P
	1	2	3	4	5	6	7	8	9	10	11	12	13	14	

XMC4[78]00 - (top view)

Figure 6 XMC4[78]00 PG-LFBGA-196 Pin Configuration (top view)

Table 10 Package Pin Mapping (cont'd)

Function	LFBGA-196	LQFP-144	LQFP-100	Pad Type	Notes
P5.3	L10	81	-	A2	
P5.4	M10	80	-	A2	
P5.5	L8	79	-	A2	
P5.6	M8	78	-	A2	
P5.7	L7	77	55	A1+	
P5.8	K6	58	-	A2	
P5.9	M6	57	-	A2	
P5.10	K5	56	-	A1+	
P5.11	L5	55	-	A1+	
P6.0	J10	101	-	A2	
P6.1	H9	100	-	A2	
P6.2	K10	99	-	A2	
P6.3	J9	98	-	A1+	
P6.4	H10	97	-	A2	
P6.5	H11	96	-	A2	
P6.6	H12	95	-	A2	
P7.0	L13	-	-	A2	
P7.1	M13	-	-	A2	
P7.2	N13	-	-	A2	
P7.3	M14	-	-	A2	
P7.4	N14	-	-	A1+	
P7.5	L14	-	-	A1+	
P7.6	K14	-	-	A1+	
P7.7	J14	-	-	A1+	
P7.8	H14	-	-	A2	
P7.9	G13	-	-	A1+	
P7.10	G14	-	-	A1+	
P7.11	F14	-	-	A1+	
P8.0	B7	-	-	A2	
P8.1	A7	-	-	A2	
P8.2	B3	-	-	A2	
P8.3	B2	-	-	A2	
P8.4	B6	-	-	A1+	

2.2.2.1 Port I/O Function Table

Table 12 Port I/O Functions

Function	Outputs						Inputs									
	ALT1	ALT2	ALT3	ALT4	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	Input	Input
P0.0	ECAT0. PHY_RST	CAN. N0_TXD	CCU80. OUT21	LEDTS0. COL2					U1C1. DX0D	ETH0. CLK_RMIIB	ERU0. 0B0					ETH0. CLKRXB
P0.1	USB. DRIVEVBUS	U1C1. DOUT0	CCU80. OUT11	LEDTS0. COL3						ETH0. CRS_DVB	ERU0. 0A0				ECAT0. P1_RX_CLKA	ETH0. RXDVB
P0.2	ECAT0. P1_TXD2	U1C1. SELO1	CCU80. OUT01		U1C0. DOUT3	EBU. AD0	U1C0. HWIN3	EBU. D0	ETH0. RXD0B		ERU0. 3B3					
P0.3	ECAT0. P1_TXD3		CCU80. OUT20		U1C0. DOUT2	EBU. AD1	U1C0. HWIN2	EBU. D1	ETH0. RXD1B			ERU1. 3B0				
P0.4	ETH0. TX_EN		CCU80. OUT10		U1C0. DOUT1	EBU. AD2	U1C0. HWIN1	EBU. D2		U1C0. DX0A	ERU0. 2B3				ECAT0. P1_RXD3A	
P0.5	ETH0. TXD0	U1C0. DOUT0	CCU80. OUT00		U1C0. DOUT0	EBU. AD3	U1C0. HWIN0	EBU. D3		U1C0. DX0B		ERU1. 3A0			ECAT0. P1_RXD2A	
P0.6	ETH0. TXD1	U1C0. SELO0	CCU80. OUT30			EBU. ADV				U1C0. DX2A	ERU0. 3B2		CCU80. IN2B		ECAT0. P1_RXD1A	
P0.7	WWDT. SERVICE_OUT	U0C0. SELO0	ECAT0. LED_ERR			EBU. AD6	DB. TDI	EBU. D6	U0C0. DX2B	DSD. DIN1A	ERU0. 2B1		CCU80. IN0A	CCU80. IN1A	CCU80. IN2A	CCU80. IN3A
P0.8	SCU. EXTCLK	U0C0. SCLKOUT	ECAT0. LED_RUN			EBU. AD7	DB. TRST	EBU. D7	U0C0. DX1B	DSD. DIN0A	ERU0. 2A1	CAN. N3_RXDA	CCU80. IN1B			
P0.9		U1C1. SELO0	CCU80. OUT12	LEDTS0. COL0	ETH0. MDO	EBU. CS1	ETH0. MDIA		U1C1. DX2A	USB. ID	ERU0. 1B0				ECAT0. P1_RX_DVA	
P0.10	ETH0. MDC	U1C1. SCLKOUT	CCU80. OUT02	LEDTS0. COL1					U1C1. DX1A		ERU0. 1A0				ECAT0. P1_TX_CLKA	
P0.11	ECAT0. P1_LINK_ACT	U1C0. SCLKOUT	CCU80. OUT31		SDMMC. RST	EBU. BREQ			ETH0. RXERB	U1C0. DX1A	ERU0. 3A2				ECAT0. P1_RXD0A	
P0.12		U1C1. SELO0	CCU40. OUT3		ECAT0. MDO	EBU. HLDA	ECAT0. MDIA	EBU. HLDA		U1C1. DX2B	ERU0. 2B2					
P0.13		U1C1. SCLKOUT	CCU40. OUT2							U1C1. DX1B	ERU0. 2A2					
P0.14		U1C0. SELO1	CCU40. OUT1		U1C1. DOUT3		U1C1. HWIN3						CCU42. IN3C			
P0.15		U1C0. SELO2	CCU40. OUT0		U1C1. DOUT2		U1C1. HWIN2						CCU42. IN2C			
P1.0	DSD. CGPWMN	U0C0. SELO0	CCU40. OUT3	ERU1. PDOUT3					U0C0. DX2A		ERU0. 3B0		CCU40. IN3A			ECAT0. P0_TX_CLKA
P1.1	DSD. CGPWMP	U0C0. SCLKOUT	CCU40. OUT2	ERU1. PDOUT2			SDMMC. SDWC		U0C0. DX1A	POSIF0. IN2A	ERU0. 3A0		CCU40. IN2A			ECAT0. P0_RX_CLKA
P1.2	ECAT0. P0_TXD3		CCU40. OUT1	ERU1. PDOUT1	U0C0. DOUT3	EBU. AD14	U0C0. HWIN3	EBU. D14		POSIF0. IN1A		ERU1. 2B0	CCU40. IN1A			
P1.3	ECAT0. P0_TX_ENA	U0C0. MCLKOUT	CCU40. OUT0	ERU1. PDOUT0	U0C0. DOUT2	EBU. AD15	U0C0. HWIN2	EBU. D15		POSIF0. IN0A		ERU1. 2A0	CCU40. IN0A			
P1.4	WWDT. SERVICE_OUT	CAN. N0_TXD	CCU80. OUT33	CCU81. OUT20	U0C0. DOUT1		U0C0. HWIN1		U0C0. DX0B	CAN. N1_RXDD	ERU0. 2B0		CCU41. IN0C			ECAT0. P0_RXD0A

Table 12 Port I/O Functions (cont'd)

Function	Outputs						Inputs									
	ALT1	ALT2	ALT3	ALT4	HWO0	HWO1	HWI0	HWI1	Input	Input	Input	Input	Input	Input	Input	Input
P4.3	U2C1. SELO2	U0C0. SELO5	CCU43. OUT3	ECAT0. MCLK									CCU43. IN3A			
P4.4		U0C0. SELO4	CCU43. OUT2		U2C1. DOUT3		U2C1. HWIN3						CCU43. IN2A			
P4.5		U0C0. SELO3	CCU43. OUT1		U2C1. DOUT2		U2C1. HWIN2						CCU43. IN1A			
P4.6		U0C0. SELO2	CCU43. OUT0		U2C1. DOUT1		U2C1. HWIN1		CAN. N2_RXDC			U2C1. DX0E	CCU43. IN0A			
P4.7	U2C1. DOUT0	CAN. N2_TXD			U2C1. DOUT0		U2C1. HWIN0		U0C0. DX0C				CCU43. IN0C			
P5.0	U2C0. DOUT0	DSD. CGPWMN	CCU81. OUT33	ERU1. PDOUT0	U2C0. DOUT0		U2C0. HWIN0		U2C0. DX0B	ETH0. RXD0D	U0C0. DX0D	ECAT0. P0_RXD0B	CCU81. IN0A	CCU81. IN1A	CCU81. IN2A	CCU81. IN3A
P5.1	U0C0. DOUT0	DSD. CGPWMP	CCU81. OUT32	ERU1. PDOUT1	U2C0. DOUT1		U2C0. HWIN1		U2C0. DX0A	ETH0. RXD1D		ECAT0. P0_RXD1B	CCU81. IN0B			
P5.2	U2C0. SCLKOUT	ECAT0. P0_LINK_ACT	CCU81. OUT23	ERU1. PDOUT2					U2C0. DX1A	ETH0. CRS_DVD		ECAT0. P0_RXD2B	CCU81. IN1B			ETH0. RXDVD
P5.3	U2C0. SELO0		CCU81. OUT22	ERU1. PDOUT3	EBU. CKE	EBU. A20			U2C0. DX2A	ETH0. RXERD			CCU81. IN2B			
P5.4	U2C0. SELO1		CCU81. OUT13		$\overline{\text{EBU.}}$ RAS	EBU. A21				ETH0. CRSD			CCU81. IN3B			ECAT0. P0_RX_CLKB
P5.5	U2C0. SELO2		CCU81. OUT12		$\overline{\text{EBU.}}$ CAS	EBU. A22				ETH0. COLD						ECAT0. P0_TX_CLKB
P5.6	U2C0. SELO3		CCU81. OUT03		EBU. BFCLKO	EBU. A23			EBU. BFCLKI							ECAT0. P0_RX_DVB
P5.7	ECAT0. SYNC0		CCU81. OUT02	LEDTS0. COLA	U2C0. DOUT2		U2C0. HWIN2					ECAT0. P0_RXD3B				
P5.8	ECAT0. P1_TX_ENA	U1C0. SCLKOUT	CCU80. OUT01	CAN. N4_TXD	EBU. SDCLKO	$\overline{\text{EBU.}}$ CS2			ETH0. RXD2A	U1C0. DX1B						
P5.9		U1C0. SELO0	CCU80. OUT20	ETH0. TX_EN	EBU. BFCLKO	$\overline{\text{EBU.}}$ CS3			ETH0. RXD3A	U1C0. DX2B					ECAT0. P1_TX_CLKB	
P5.10		U1C0. MCLKOUT	CCU80. OUT10	LEDTS0. LINE7	LEDTS0. EXTENDED7		LEDTS0. TSIN7A		ETH0. CLK_TXA		CAN. N5_RXDA					
P5.11		U1C0. SELO1	CCU80. OUT00	CAN. N5_TXD					ETH0. CRSA							
P6.0	ETH0. TXD2	U0C1. SELO1	CCU81. OUT31	ECAT0. PHY_CLK25	DB. ETM_TRACECLK	EBU. A16										
P6.1	ETH0. TXD3	U0C1. SELO0	CCU81. OUT30	ECAT0. P0_TX_ENA	DB. ETM_TRACEDATA3	EBU. A17			U0C1. DX2C							
P6.2	ETH0. TXER	U0C1. SCLKOUT	CCU43. OUT3	ECAT0. P0_TXD0	DB. ETM_TRACEDATA2	EBU. A18			U0C1. DX1C							
P6.3			CCU43. OUT2	ECAT0. P0_LINK_ACT					U0C1. DX0C	ETH0. RXD3B						
P6.4		U0C1. DOUT0	CCU43. OUT1	ECAT0. P0_TXD1	EBU. SDCLKO	EBU. A19			EBU. SDCLKI	ETH0. RXD2B						
P6.5	CAN. N3_TXD	U0C1. MCLKOUT	CCU43. OUT0	ECAT0. P0_TXD2	DB. ETM_TRACEDATA1	$\overline{\text{EBU.}}$ BC2			DSD. DIN3A	ETH0. CLK_RMIID		U2C0. DX0D				ETH0. CLKRXD

3.1.2 Absolute Maximum Ratings

Stresses above the values listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Table 13 Absolute Maximum Rating Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Storage temperature	T_{ST}	SR	-65	–	150	°C	–
Junction temperature	T_J	SR	-40	–	150	°C	–
Voltage at 3.3 V power supply pins with respect to V_{SS}	V_{DDP}	SR	–	–	4.3	V	–
Voltage on any Class A and dedicated input pin with respect to V_{SS}	V_{IN}	SR	-1.0	–	V_{DDP} + 1.0 or max. 4.3	V	whichever is lower
Voltage on any analog input pin with respect to V_{AGND}	V_{AIN} V_{AREF}	SR	-1.0	–	V_{DDP} + 1.0 or max. 4.3	V	whichever is lower
Input current on any pin during overload condition	I_{IN}	SR	-10	–	+10	mA	
Absolute maximum sum of all input circuit currents for one port group during overload condition[1)]	ΣI_{IN}	SR	-25	–	+25	mA	
Absolute maximum sum of all input circuit currents during overload condition	ΣI_{IN}	SR	-100	–	+100	mA	

1) The port groups are defined in **Table 17**.

Figure 10 explains the input voltage ranges of V_{IN} and V_{AIN} and its dependency to the supply level of V_{DDP}.The input voltage must not exceed 4.3 V, and it must not be more than 1.0 V above V_{DDP}. For the range up to V_{DDP} + 1.0 V also see the definition of the overload conditions in **Section 3.1.3**.

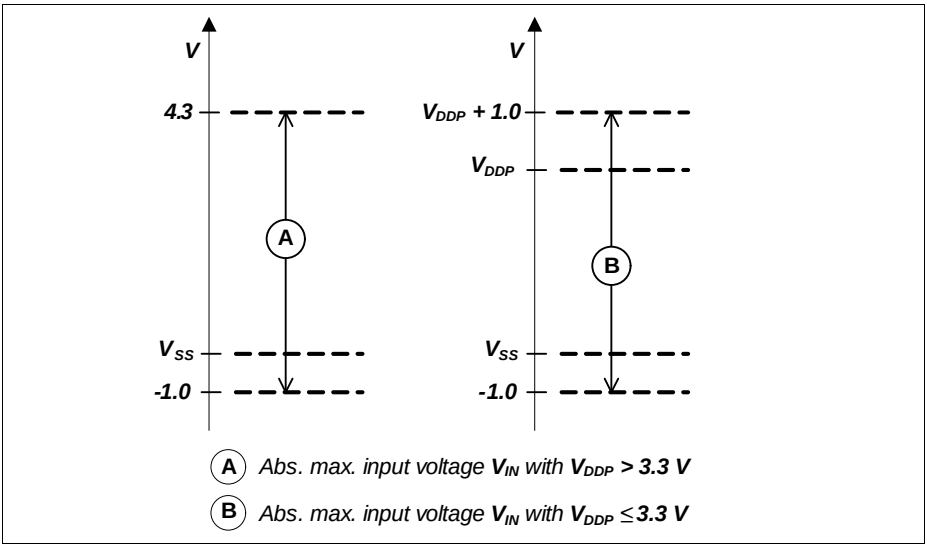


Figure 10 Absolute Maximum Input Voltage Ranges

3.1.3 Pin Reliability in Overload

When receiving signals from higher voltage devices, low-voltage devices experience overload currents and voltages that go beyond their own IO power supplies specification.

Table 14 defines overload conditions that will not cause any negative reliability impact if all the following conditions are met:

- full operation life-time is not exceeded
- **Operating Conditions** are met for
  - pad supply levels (V_{DDP} or V_{DDA})
  - temperature

If a pin current is outside of the **Operating Conditions** but within the overload conditions, then the parameters of this pin as stated in the Operating Conditions can no longer be guaranteed. Operation is still possible in most cases but with relaxed parameters.

Note: An overload condition on one or more pins does not require a reset.

Note: A series resistor at the pin to limit the current to the maximum permitted overload current is sufficient to handle failure situations like short to battery.

Table 23 Standard Pads Class_A2

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Input Leakage current	I_{OZA2} CC	-6		6	µA	0 V ≤ V_{IN} < 0.5*V_{DDP} - 1 V; 0.5*V_{DDP} + 1 V <V_{IN} ≤ V_{DDP}
		-3		3	µA	0.5*V_{DDP} - 1 V < V_{IN} < 0.5*V_{DDP} + 1 V
Input high voltage	V_{IHA2} SR	0.6 × V_{DDP}		V_{DDP} + 0.3	V	max. 3.6 V
Input low voltage	V_{ILA2} SR	-0.3		0.36 × V_{DDP}	V	
Output high voltage, POD = weak	V_{OHA2} CC	V_{DDP} - 0.4		–	V	I_{OH} ≥ -400 µA
		2.4		–	V	I_{OH} ≥ -500 µA
Output high voltage, POD = medium		V_{DDP} - 0.4		–	V	I_{OH} ≥ -1.4 mA
		2.4		–	V	I_{OH} ≥ -2 mA
Output high voltage, POD = strong		V_{DDP} - 0.4		–	V	I_{OH} ≥ -1.4 mA
		2.4		–	V	I_{OH} ≥ -2 mA
Output low voltage, POD = weak	V_{OLA2} CC	–		0.4	V	I_{OL} ≤ 500 µA
Output low voltage, POD = medium		–		0.4	V	I_{OL} ≤ 2 mA
Output low voltage, POD = strong		–		0.4	V	I_{OL} ≤ 2 mA

Table 24 HIB_IO Class_A1 special Pads

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.		Max.		
Input leakage current	I_{OZHIB} CC	-500		500	nA	$0\ V \le V_{IN} \le V_{BAT}$
Input high voltage	V_{IHHIB} SR	$0.6 \times V_{BAT}$		V_{BAT} + 0.3	V	max. 3.6 V
Input low voltage	V_{ILHIB} SR	-0.3		$0.36 \times V_{BAT}$	V	
Input Hysteresis for HIB_IO pins[1]	$HYSHIB$ CC	$0.1 \times V_{BAT}$		–	V	$V_{BAT} \ge 3.13\ V$
		$0.06 \times V_{BAT}$		–	V	$V_{BAT} < 3.13\ V$
Output high voltage, POD[1] = medium	V_{OHHIB} CC	V_{BAT} - 0.4		–	V	$I_{OH} \ge$ -1.4 mA
Output low voltage	V_{OLHIB} CC	–		0.4	V	$I_{OL} \le 2$ mA
Fall time	t_{FHIB} CC	–		50	ns	$V_{BAT} \ge 3.13\ V$, $C_L = 50$ pF
		–		100	ns	$V_{BAT} < 3.13\ V$, $C_L = 50$ pF
Rise time	t_{RHIB} CC	–		50	ns	$V_{BAT} \ge 3.13\ V$, $C_L = 50$ pF
		–		100	ns	$V_{BAT} < 3.13\ V$, $C_L = 50$ pF

1) Hysteresis is implemented to avoid metastable states and switching due to internal ground bounce. It can not be guaranteed that it suppresses switching due to external system noise.

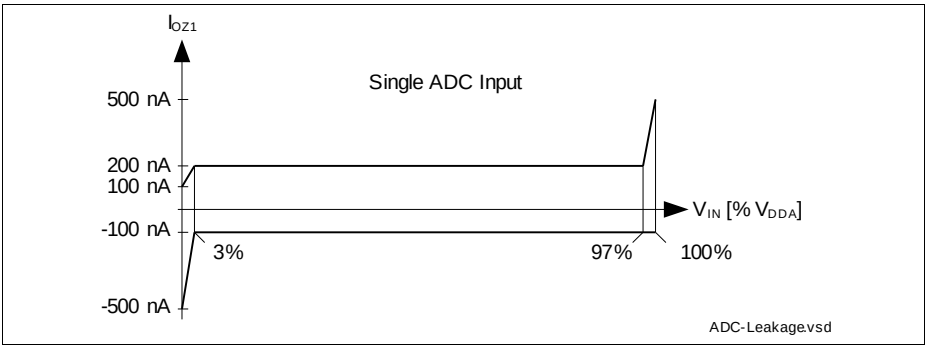


Figure 16 VADC Analog Input Leakage Current

Conversion Time

Table 26 Conversion Time (Operating Conditions apply)

Parameter	Symbol	Values	Unit	Note
Conversion time	t_C CC	$2 \times T_{ADC}$ + $(2 + N + STC + PC + DM) \times T_{ADCI}$	µs	N = 8, 10, 12 for N-bit conversion $T_{ADC} = 1 / f_{PERIPH}$ $T_{ADCI} = 1 / f_{ADCI}$

- STC defines additional clock cycles to extend the sample time
- PC adds two cycles if post-calibration is enabled
- DM adds one cycle for an extended conversion time of the MSB

Conversion Time Examples

System assumptions:
f_{ADC} = 144 MHz i.e. t_{ADC} = 6.9 ns, DIVA = 3, f_{ADCI} = 36 MHz i.e. t_{ADCI} = 27.8 ns
According to the given formulas the following minimum conversion times can be achieved (STC = 0, DM = 0):

12-bit post-calibrated conversion (PC = 2):
$t_{CN12C} = (2 + 12 + 2) \times t_{ADCI} + 2 \times t_{ADC} = 16 \times 27.8$ ns $+ 2 \times 6.9$ ns = 459 ns
12-bit uncalibrated conversion:
$t_{CN12} = (2 + 12) \times t_{ADCI} + 2 \times t_{ADC} = 14 \times 27.8$ ns $+ 2 \times 6.9$ ns = 403 ns
10-bit uncalibrated conversion:
$t_{CN10} = (2 + 10) \times t_{ADCI} + 2 \times t_{ADC} = 12 \times 27.8$ ns $+ 2 \times 6.9$ ns = 348 ns
8-bit uncalibrated:
$t_{CN8} = (2 + 8) \times t_{ADCI} + 2 \times t_{ADC} = 10 \times 27.8$ ns $+ 2 \times 6.9$ ns = 292 ns

3.2.5 Die Temperature Sensor

The Die Temperature Sensor (DTS) measures the junction temperature T_J.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 29 Die Temperature Sensor Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Temperature sensor range	T_{SR}	SR	-40	–	150	°C	
Linearity Error (to the below defined formula)	ΔT_{LE}	CC	–	±1	–	°C	per $\Delta T_J \leq 30$ °C
Offset Error	ΔT_{OE}	CC	–	±6	–	°C	$\Delta T_{OE} = T_J - T_{DTS}$ $V_{DDP} \leq 3.3$ V[1]
Measurement time	t_M	CC	–	–	100	µs	
Start-up time after reset inactive	t_{TSST}	SR	–	–	10	µs	

1) At V_{DDP_max} = 3.63 V the typical offset error increases by an additional ΔT_{OE} = ±1 °C.

The following formula calculates the temperature measured by the DTS in [°C] from the RESULT bit field of the DTSSTAT register.

Temperature T_{DTS} = (RESULT - 605) / 2.05 [°C]

This formula and the values defined in **Table 29** apply with the following calibration values:

- DTSCON.BGTRIM = 8_H
- DTSCON.REFTRIM = 4_H

Table 32 OSC_XTAL Parameters

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Input frequency	f_{OSC} SR	4	–	40	MHz	Direct Input Mode selected
		4	–	25	MHz	External Crystal Mode selected
Oscillator start-up time[1)2)]	t_{OSCS} CC	–	–	10	ms	
Input voltage at XTAL1	V_{IX} SR	-0.5	–	V_{DDP} + 0.5	V	
Input amplitude (peak-to-peak) at XTAL1[2)3)]	V_{PPX} SR	0.4 × V_{DDP}	–	V_{DDP} + 1.0	V	
Input high voltage at XTAL1[4)]	V_{IHBX}SR	1.0	–	V_{DDP} + 0.5	V	
Input low voltage at XTAL1[4)]	V_{ILBX} SR	-0.5	–	0.4	V	
Input leakage current at XTAL1	I_{ILX1} CC	-100	–	100	nA	Oscillator power down 0 V ≤ V_{IX} ≤ V_{DDP}

1) t_{OSCS} is defined from the moment the oscillator is enabled wih SCU_OSCHPCTRL.MODE until the oscillations reach an amplitude at XTAL1 of 0.4 * V_{DDP}.

2) The external oscillator circuitry must be optimized by the customer and checked for negative resistance and amplitude as recommended and specified by crystal suppliers.

3) If the shaper unit is enabled and not bypassed.

4) If the shaper unit is bypassed, dedicated DC-thresholds have to be met.

3.3.9 Peripheral Timing

3.3.9.1 Delta-Sigma Demodulator Digital Interface Timing

The following parameters are applicable for the digital interface of the Delta-Sigma Demodulator (DSD).
The data timing is relative to the active clock edge. Depending on the operation mode of the connected modulator that can be the rising and falling clock edge.

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Table 45 DSD Interface Timing Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
MCLK period in master mode	t_1	CC	33.3	–	–	ns	$t_1 \geq 4 \times t_{PERIPH}$ [1]
MCLK high time in master mode	t_2	CC	9	–	–	ns	$t_2 > t_{PERIPH}$ [1]
MCLK low time in master mode	t_3	CC	9	–	–	ns	$t_3 > t_{PERIPH}$ [1]
MCLK period in slave mode	t_1	SR	33.3	–	–	ns	$t_1 \geq 4 \times t_{PERIPH}$ [1]
MCLK high time in slave mode	t_2	SR	t_{PERIPH}	–	–	ns	[1]
MCLK low time in slave mode	t_3	SR	t_{PERIPH}	–	–	ns	[1]
DIN input setup time to the active clock edge	t_4	SR	t_{PERIPH} + 4	–	–	ns	[1]
DIN input hold time from the active clock edge	t_5	SR	t_{PERIPH} + 3	–	–	ns	[1]

1) $t_{PERIPH} = 1 / f_{PERIPH}$

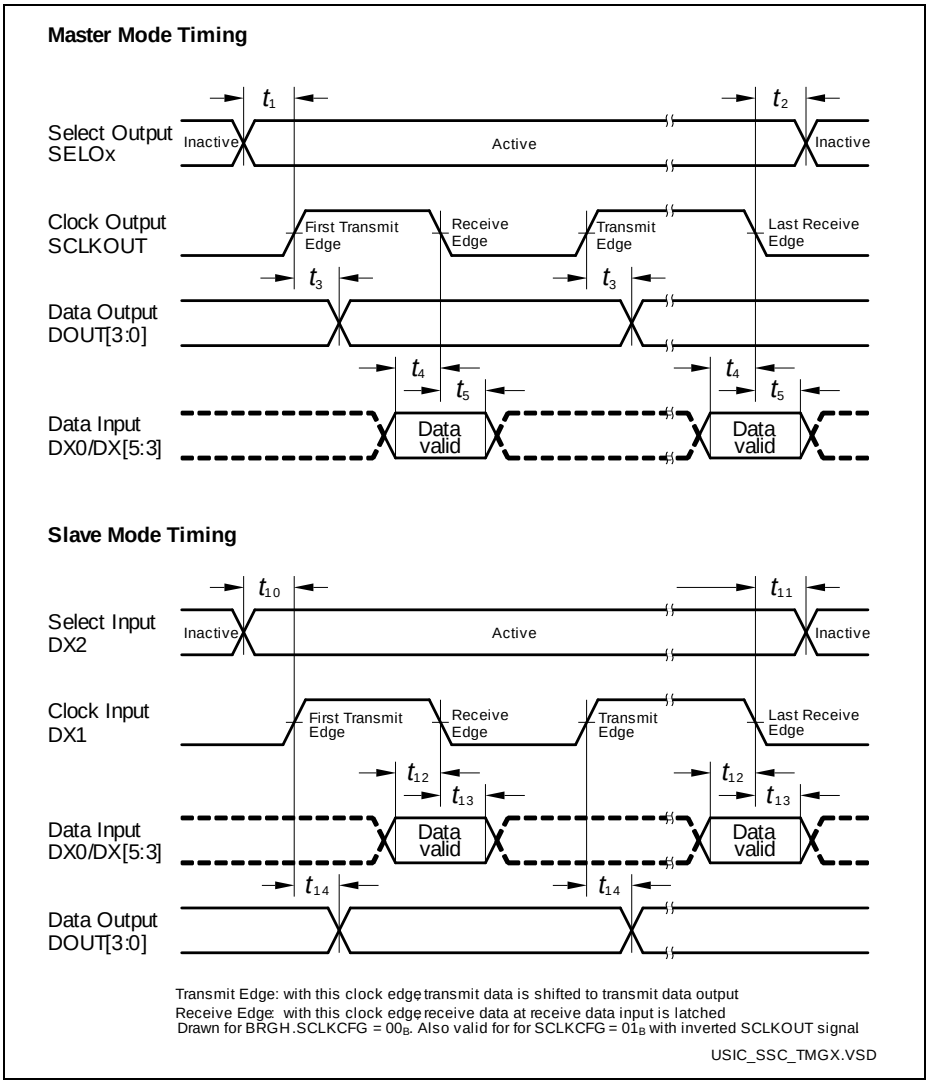


Figure 33 USIC - SSC Master/Slave Mode Timing

Note: This timing diagram shows a standard configuration, for which the slave select signal is low-active, and the serial clock signal is not shifted and not inverted.

3.3.10.3 EBU Arbitration Signal Timing

Note: These parameters are not subject to production test, but verified by design and/or characterization.

Note: Operating Conditions apply.

Table 60 EBU Arbitration Signal Timing Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
Output delay from BFCLKO rising edge	t_1	CC	–	–	16	ns	C_L = 50 pF
Data setup to BFCLKO falling edge	t_2	SR	11	–	–	ns	–
Data hold from BFCLKO falling edge	t_3	SR	2	–	–	ns	–

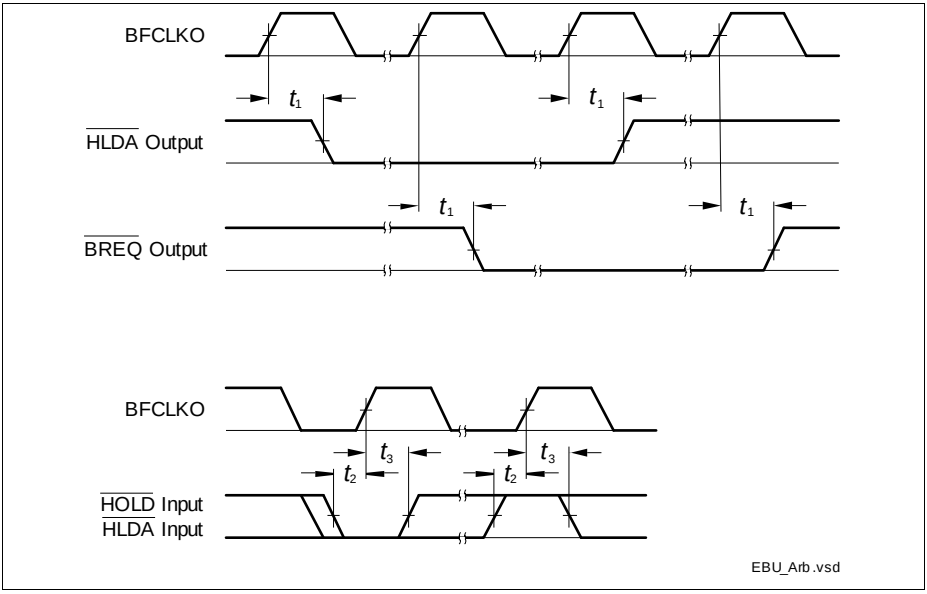


Figure 46 EBU Arbitration Signal Timing

3.3.12.4 ETH RMII Parameters

In the following, the parameters of the RMII (Reduced Media Independent Interface) are described.

Table 66 ETH RMII Signal Timing Parameters

Parameter	Symbol		Values			Unit	Note / Test Condition
			Min.	Typ.	Max.		
ETH_RMII_REF_CL clock period	t_{13}	SR	20	–	–	ns	C_L = 25 pF; 50 ppm
ETH_RMII_REF_CL clock high time	t_{14}	SR	7	–	13	ns	C_L = 25 pF
ETH_RMII_REF_CL clock low time	t_{15}	SR	7	–	13	ns	
ETH_RMII_RXD[1:0], ETH_RMII_CRS setup time	t_{16}	SR	4	–	–	ns	
ETH_RMII_RXD[1:0], ETH_RMII_CRS hold time	t_{17}	SR	2	–	–	ns	
ETH_RMII_TXD[1:0], ETH_RMII_TXEN data valid	t_{18}	CC	4	–	15	ns	

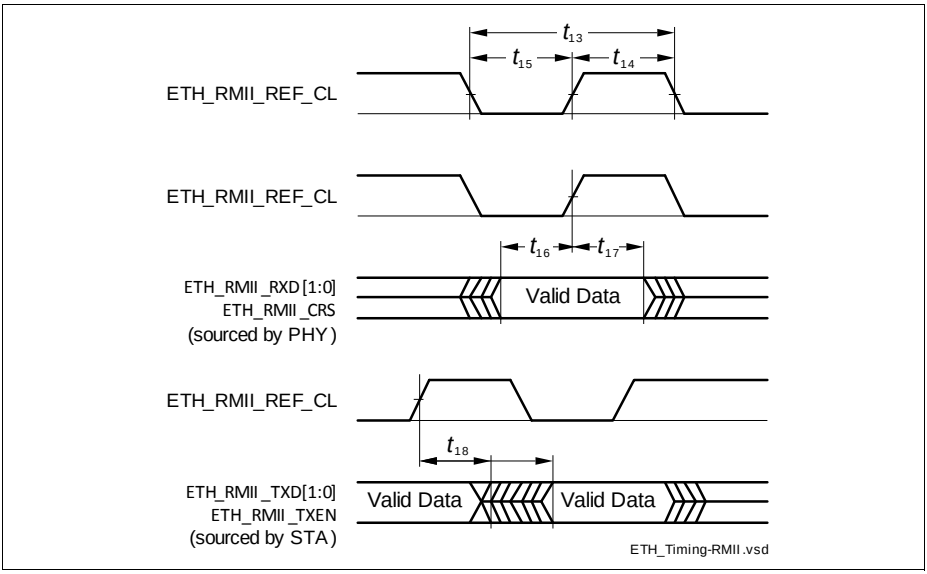


Figure 54 ETH RMII Signal Timing

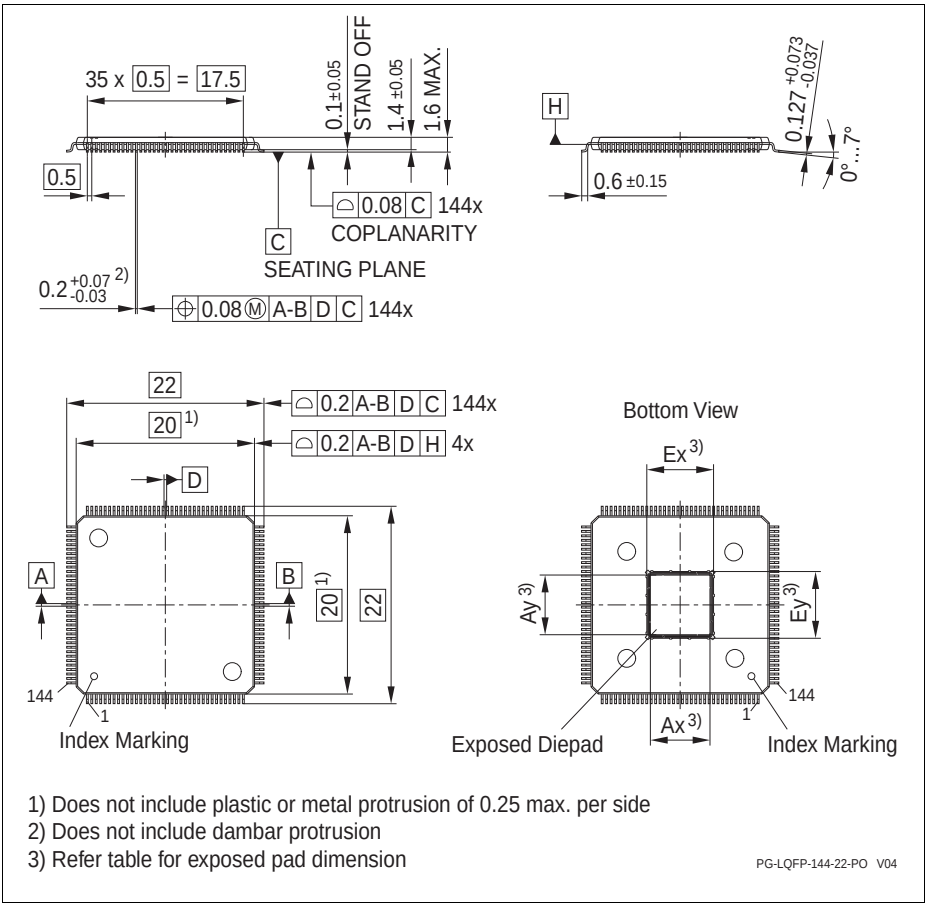


Figure 60 PG-LQFP-144-24 (Plastic Green Low Profile Quad Flat Package)